Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

36.9 millimeters

Mounting Facility Quantity:

1

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Do-5

Mounting Method:

Threaded stud

Overall Width Across Flats:

17.0 millimeters

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

150.0 repetitive peak reverse voltage and 0.8 forward voltage, dc and 150.0 working peak reverse voltage and 150.0 reverse voltage, instantaneous

Current Rating Per Characteristic:

40.00 amperes forward current, average

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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